

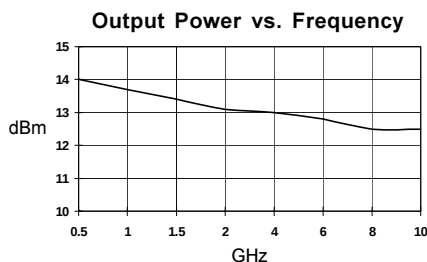


Product Description

Sirenza Microdevices' SNA-176 is a GaAs monolithic broadband amplifier (MMIC) housed in a low-cost surface mountable stripline package. At 1950 MHz, this amplifier provides 12dB of gain when biased at 50mA.

External DC decoupling capacitors determine low frequency response. The use of an external resistor allows for bias flexibility and stability.

These unconditionally stable amplifiers are designed for use as general purpose 50 ohm gain blocks. Also available in chip form (SNA-100), its small size (0.33mm x 0.33mm) and gold metallization makes it an ideal choice for use in hybrid circuits.



SNA-176

DC-10 GHz, Cascadable GaAs MMIC Amplifier



Product Features

- Cascadable 50 Ohm Gain Block
- 12dB Gain, +13dBm P1dB
- 1.5:1 Input and Output VSWR
- Operates From Single Supply
- Low Cost Stripline Mount Ceramic Package
- Hermetically Sealed

Applications

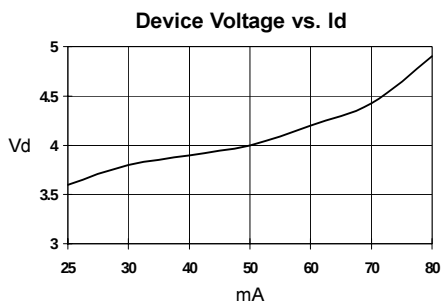
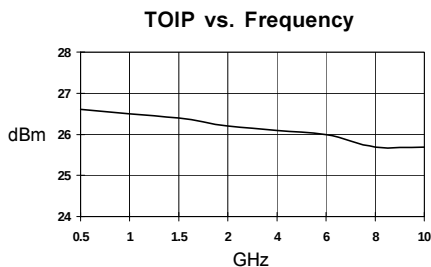
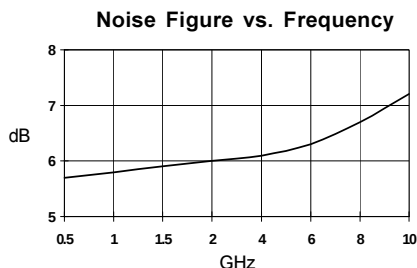
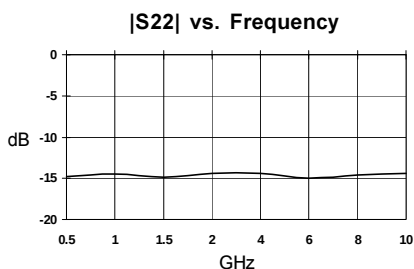
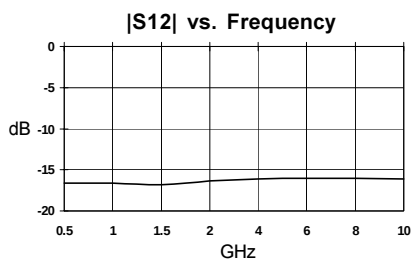
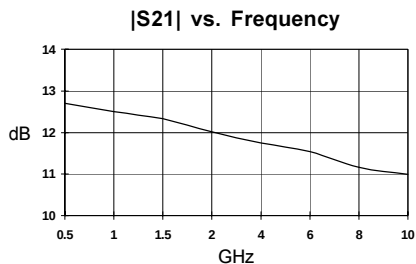
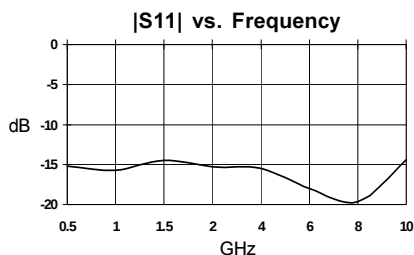
- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Symbol	Parameter	Units	Frequency	Min.	Typ.	Max.
G_P	Small Signal Power Gain	dB dB dB	850 MHz 1950 MHz 2400 MHz	11.5	12.5 12.0 11.8	
G_F	Gain Flatness	dB	0.1-8 GHz		+/- 0.5	
BW3dB	3dB Bandwidth	GHz			10.0	
P_{1dB}	Output Power at 1dB Compression	dBm	1950 MHz		13.0	
OIP_3	Output Third Order Intercept Point	dBm	1950 MHz		26.0	
NF	Noise Figure	dB	1950 MHz		6.0	
VSWR	Input / Output	-	0.1-10 GHz		1.5:1	
ISOL	Reverse Isolation	dB	0.1-10 GHz		16	
V_D	Device Operating Voltage	V		3.3	3.8	4.3
I_D	Device Operating Current	mA		45	50	55
dG/dT	Device Gain Temperature Coefficient	dB/°C			-0.0015	
R_{TH} , j-I	Thermal Resistance (junction to lead)	°C/W			420	

Test Conditions: $V_S = 8\text{ V}$ $I_D = 50\text{ mA Typ.}$ OIP_3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm
 $R_{BIAS} = 82\text{ Ohms}$ $T_L = 25^\circ\text{C}$ $Z_S = Z_L = 50\text{ Ohms}$

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Typical Performance at 25 °C ($V_{ds} = 3.8V$, $I_{ds} = 50mA$)



Absolute Maximum Ratings

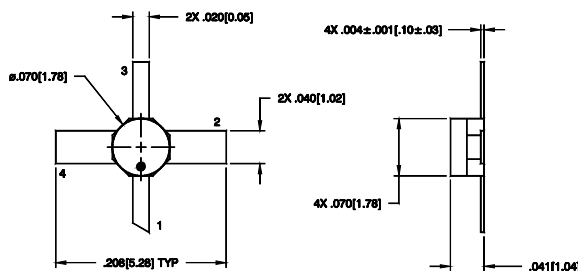
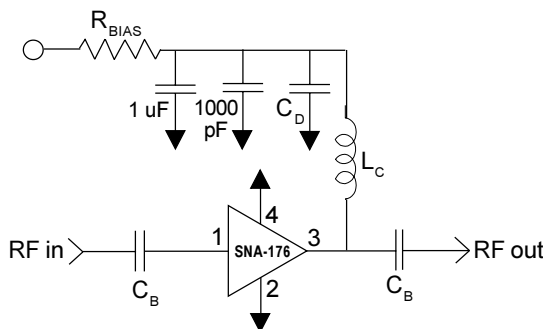
Parameter	Absolute Limit
Max. Device Current (I_D)	70 mA
Max. Device Voltage (V_D)	6 V
Max. RF Input Power	+10 dBm
Max. Junction Temp. (T_J)	+150°C
Operating Temp. Range (T_L)	-40°C to +85°C
Max. Storage Temp.	+150°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

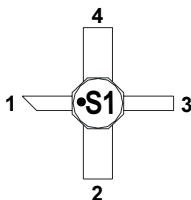
$$I_D V_D < (T_J - T_L) / R_{TH} j-I$$

Typical Application Circuit



Part Identification Marking

The part will be marked with an "S1" designator on the top surface of the package.



Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.

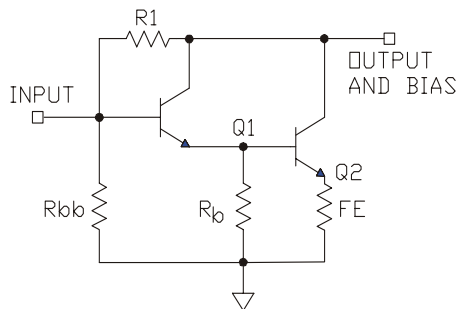
Application Circuit Element Values

Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _C	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_D=50mA

Supply Voltage(V _S)	6 V	8 V	10 V	12 V
R _{BIAS}	43 Ω	82 Ω	120 Ω	160 Ω

Note: R_{BIAS} provides DC bias stability over temperature.



Simplified Schematic of MMIC

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SNA-176-TR1	7"	1000
SNA-176-TR2	13"	3000
SNA-176-TR3	13"	5000